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Microsemi

Power Matters[™]

87.50 W

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Overview Diagrams

Diagram

Electrical Rating	Symbo	ol	Min	Ту	р	Max	Unit
Collector to Emitter Saturation Voltage	V _{CE(sa}	t)				1.00	V
DC Current Gain	HFE		25.00			100.00	
Maximum Electrical Rating		Syı	mbol	Min	Тур	Max	Unit
Maximum Electrical Rating Breakdown Voltage, Collector-Base (Emitter Ope	n)	_	mbol R(CBO)	Min	Тур	Max 60.00	Unit
· · · · · · · · · · · · · · · · · · ·	n)	_		Min	Тур		

This part can be found in the following product categories:

Emitter-Base Voltage (Collector Open)

Power Dissipation, Total

- → Discretes → Transistors → BJT(BiPolar Junction Transistor) → PNP Transistor
- Non-Radiation Hardened Devices Transistors BJT(BiPolar Junction Transistor) PNP Transistor

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